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DUAL DIGIT LED DISPLAY (0.5 Inch)



Lead-Free Parts

LDD505/61-XX/P10-PF

DATA SHEET

DOC. NO : QW0905-LDD505/61-XX/P10-PF

REV. : A

DATE : 18 - Apr. - 2008



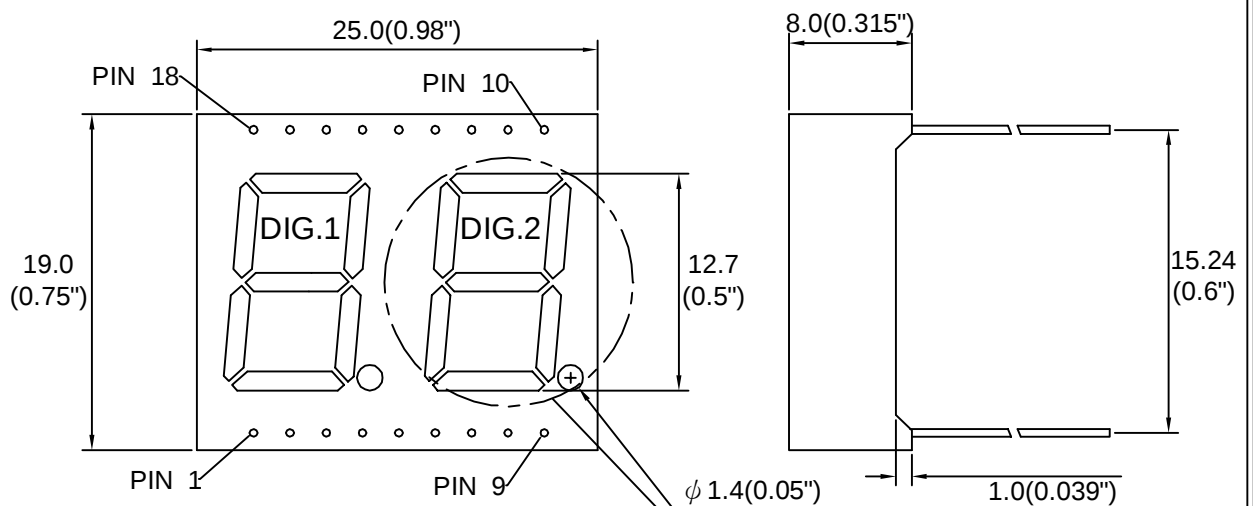
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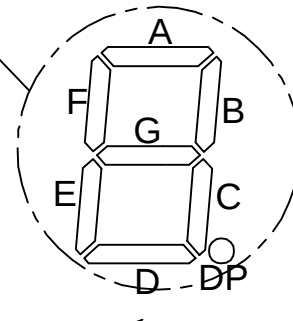
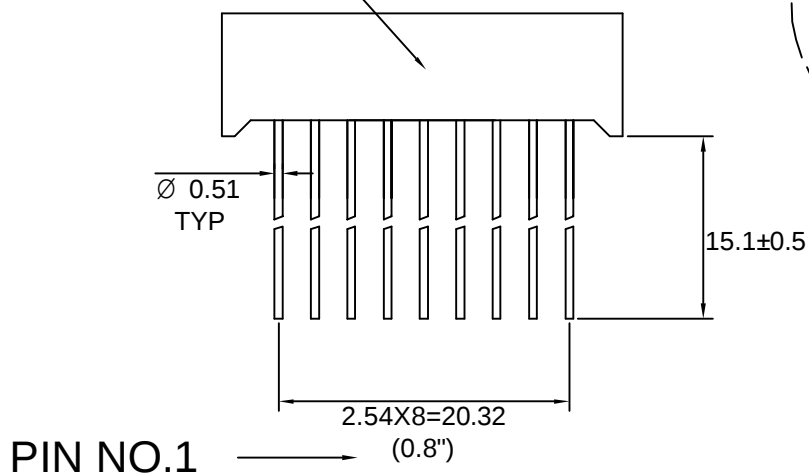
PART NO. LDD505/61-XX/P10-PF

Page 1/8

Package Dimensions



LDD505/61-XX/P10-PF
LIGITEK

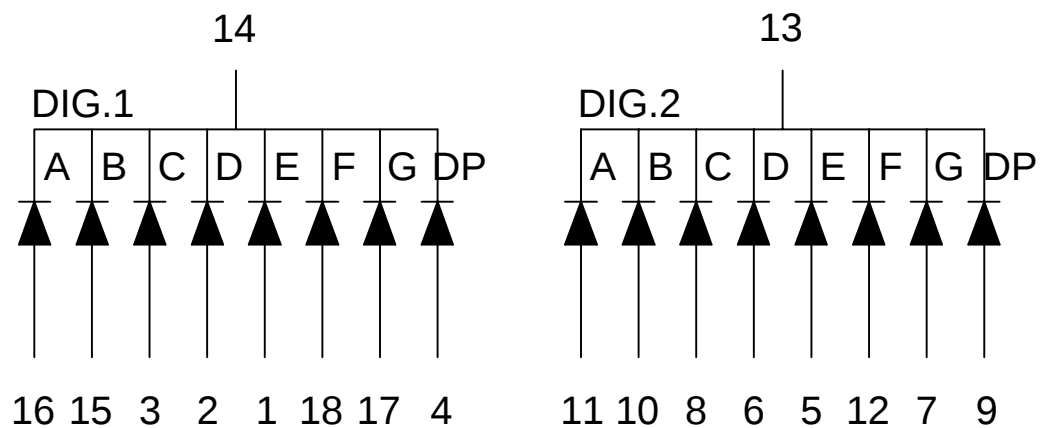


Note : 1.All dimension are in millimeters and (Inch) tolerance is $\pm 0.25\text{mm}$ unless otherwise noted.
2.Specifications are subject to change without notice.

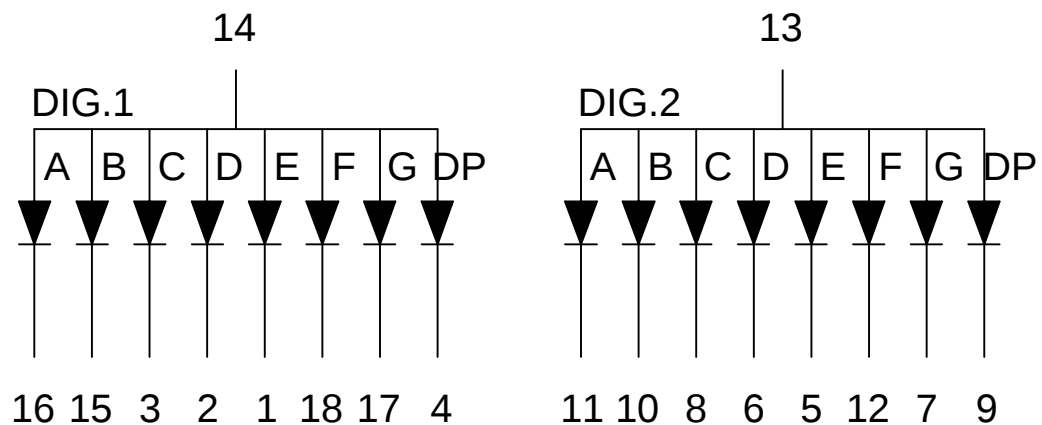


Internal Circuit Diagram

LDD5051-XX/P10-PF



LDD5061-XX/P10-PF



**Electrical Connection**

PIN NO.	LDD5051-XX/P10-PF	PIN NO.	LDD5061-XX/P10-PF
1	Anode E Dig.1	1	Cathode E Dig.1
2	Anode D Dig.1	2	Cathode D Dig.1
3	Anode C Dig.1	3	Cathode C Dig.1
4	Anode DP Dig.1	4	Cathode DP Dig.1
5	Anode E Dig.2	5	Cathode E Dig.2
6	Anode D Dig.2	6	Cathode D Dig.2
7	Anode G Dig.2	7	Cathode G Dig.2
8	Anode C Dig.2	8	Cathode C Dig.2
9	Anode DP Dig.2	9	Cathode DP Dig.2
10	Anode B Dig.2	10	Cathode B Dig.2
11	Anode A Dig.2	11	Cathode A Dig.2
12	Anode F Dig.2	12	Cathode F Dig.2
13	Common Cathode Dig.2	13	Common Anode Dig.2
14	Common Cathode Dig.1	14	Common Anode Dig.1
15	Anode B Dig.1	15	Cathode B Dig.1
16	Anode A Dig.1	16	Cathode A Dig.1
17	Anode G Dig.1	17	Cathode G Dig.1
18	Anode F Dig.1	18	Cathode F Dig.1



Absolute Maximum Ratings at Ta=25 °C

Parameter	Symbol	Ratings	UNIT
		H	
Forward Current Per Chip	I _F	20	mA
Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width)	I _{FP}	60	mA
Power Dissipation Per Chip	PD	50	mW
Reverse Current Per Any Chip	I _r	10	μA
Operating Temperature	T _{opr}	-25 ~ +85	°C
Storage Temperature	T _{stg}	-25 ~ +85	°C
Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260 °C			

Part Selection And Application Information(Ratings at 25°C)

PART NO	CHIP		common cathode or anode	λ P (nm)	$\Delta \lambda$ (nm)	Electrical					IV-M
	Material	Emitted				Vf(v)			Iv(mcd)		
						Min.	Typ.	Max.	Min.	Typ.	
LDD5051-XX/P10-PF	GaP	Red	Common Cathode	697	90	1.7	2.1	2.6	0.5	0.8	2:1
LDD5061-XX/P10-PF			Common Anode								

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.

2. The luminous intensity data did not including ±15% testing tolerance.

**Test Condition For Each Parameter**

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	V _f	volt	I _f =20mA
Luminous Intensity Per Chip	I _v	mcd	I _f =10mA
Peak Wavelength	λ P	nm	I _f =20mA
Spectral Line Half-Width	$\Delta \lambda$	nm	I _f =20mA
Reverse Current Any Chip	I _r	μ A	V _r =5V
Luminous Intensity Matching Ratio	IV-M		



Typical Electro-Optical Characteristics Curve

H CHIP

Fig.1 Forward current vs. Forward Voltage

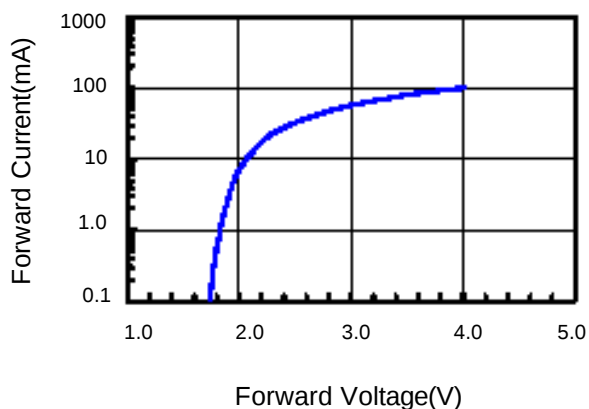


Fig.2 Relative Intensity vs. Forward Current

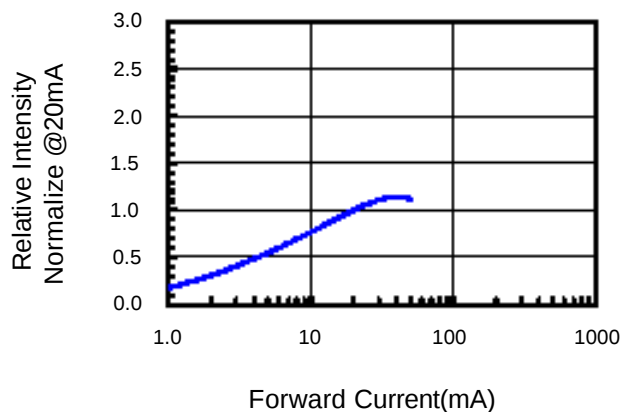


Fig.3 Forward Voltage vs. Temperature

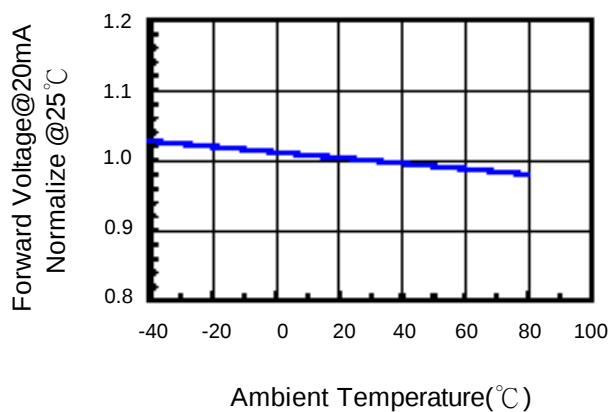


Fig.4 Relative Intensity vs. Temperature

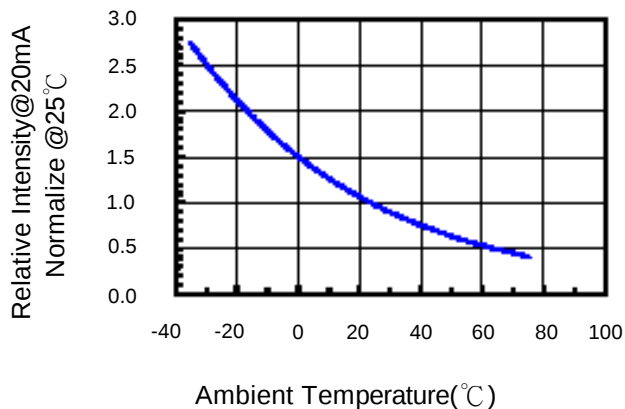
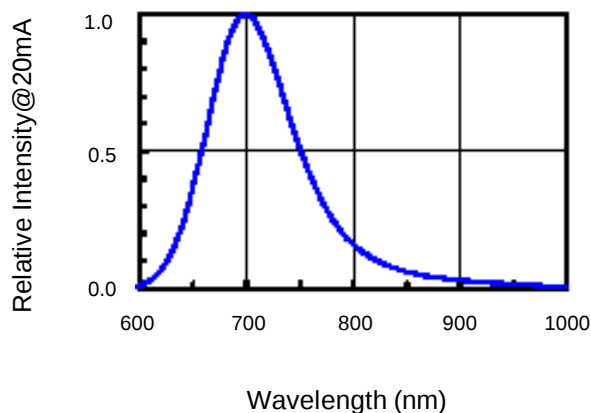


Fig.5 Relative Intensity vs. Wavelength



**Soldering Condition(Pb-Free)****1.Iron:**

Soldering Iron:30W Max

Temperature 350 °C Max

Soldering Time:3 Seconds Max(One time only)

Distance:Solder Temperature 1/16 Inch Below Seating
Plane For 3 Seconds At 260 °C**2.Wave Soldering Profile**

Dip Soldering

Preheat: 120°C Max

Preheat time: 60seconds Max

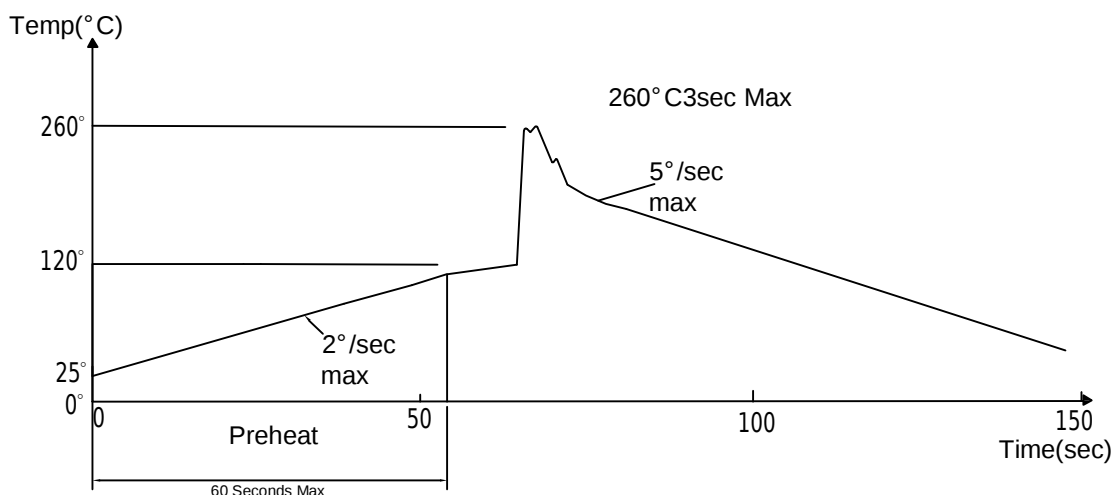
Ramp-up

2° C/sec(max)

Ramp-Down:-5° C/sec(max)

Solder Bath:260°C Max

Dipping Time:3 seconds Max

Distance:Solder Temperature 1/16 Inch Below Seating
Plane For 3 Seconds At 260° C

Note: 1.Wave solder should not be made more than one time.

2.You can just only select one of the soldering conditions as above.

**Reliability Test:**

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 °C ±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 °C ±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 °C ±5°C 2.RH=90%~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 °C ±5°C & -40 °C ±5°C (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 °C ±5°C 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 °C ±5°C 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2